

Data sheet acquired from Harris Semiconductor SCHS183C

High-Speed CMOS Logic Octal D-Type Flip-Flop, 3-State Positive-Edge Triggered

February 1998 - Revised May 2004

### Features

- · Buffered Inputs
- Common Three-State Output Enable Control
- Three-State Outputs
- . Bus Line Driving Capability
- Typical Propagation Delay (Clock to Q) = 15ns at V<sub>CC</sub> = 5V, C<sub>L</sub> = 15pF, T<sub>A</sub> = 25°C
- Fanout (Over Temperature Range)
  - Standard Outputs...... 10 LSTTL Loads
  - Bus Driver Outputs ...... 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2-V to 6-V Operation
  - High Noise Immunity:  $N_{IL}$  = 30%,  $N_{IH}$  = 30% of  $V_{CC}$  at  $V_{CC}$  = 5V
- HCT Types
  - 4.5-V to 5.5-V Operation
  - Direct LSTTL Input Logic Compatibility,
     V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)

### Description

The 'HC374, 'HCT374, 'HC574, and 'HCT574 are octal D-type flip-flops with 3-state outputs and the capability to drive 15 LSTTL loads. The eight edge-triggered flip-flops enter data into their registers on the LOW to HIGH transition of clock (CP). The output enable  $(\overline{OE})$  controls the 3-state outputs and is independent of the register operation. When  $\overline{OE}$  is HIGH, the outputs are in the high-impedance state. The 374 and 574 are identical in function and differ only in their pinout arrangements.

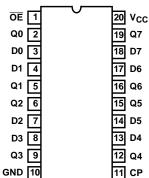
### Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC374F3A	-55 to 125	20 Ld CERDIP
CD54HC574F3A	-55 to 125	20 Ld CERDIP
CD54HCT374F3A	-55 to 125	20 Ld CERDIP
CD54HCT574F3A	-55 to 125	20 Ld CERDIP
CD74HC374E	-55 to 125	20 Ld PDIP
CD74HC374M	-55 to 125	20 Ld SOIC
CD74HC374M96	-55 to 125	20 Ld SOIC
CD74HC574E	-55 to 125	20 Ld PDIP
CD74HC574M	-55 to 125	20 Ld SOIC
CD74HC574M96	-55 to 125	20 Ld SOIC
CD74HCT374E	-55 to 125	20 Ld PDIP
CD74HCT374M	-55 to 125	20 Ld SOIC
CD74HCT374M96	-55 to 125	20 Ld SOIC
CD74HCT574E	-55 to 125	20 Ld PDIP
CD74HCT574M	-55 to 125	20 Ld SOIC
CD74HCT574M96	-55 to 125	20 Ld SOIC
CD74HCT574PWR	-55 to 125	20 Ld TSSOP

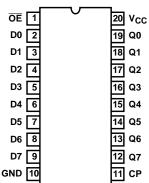
NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel.

### **Pinouts**

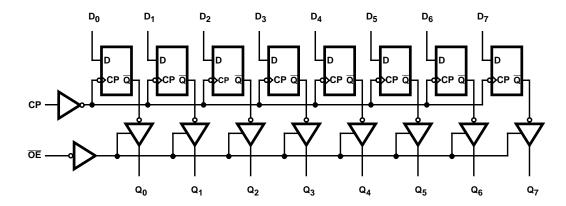
CD54HC374, CD54HCT374 (CERDIP) CD74HC374, CD74HCT374 (PDIP, SOIC) TOP VIEW



CD54HC574, CD54HCT574 (CERDIP) CD74HC574 (PDIP, SOIC) CD74HCT574 (PDIP, SOIC, TSSOP) TOP VIEW



### Functional Diagram



### **TRUTH TABLE**

	INPUTS		OUTPUT
ŌĒ	СР	Qn	
L	<b>↑</b>	Н	Н
L	<b>↑</b>	L	L
L	L	X	Q0
Н	Х	Х	Z

H = High Level (Steady State)

L = Low Level (Steady State)

X= Don't Care

↑= Transition from Low to High Level

Q0= The level of Q before the indicated steady-state input conditions were established

Z = High Impedance State

# $\begin{tabular}{lll} \textbf{Absolute Maximum Ratings} \\ DC & Supply & Voltage, $V_{CC}$ & -0.5V to 7V \\ DC & Input Diode Current, $I_{IK}$ & $-0.5V$ or $V_I > V_{CC} + 0.5V$ & <math>\pm 20\text{mA}$ \\ DC & Output Diode Current, $I_{OK}$ & $-0.5V$ or $V_O > V_{CC} + 0.5V$ & <math>\pm 20\text{mA}$ \\ DC & Drain Current, per Output, $I_O$ & $\pm 20\text{mA}$ \\ DC & Drain Current, per Output, $I_O$ & $\pm 35\text{mA}$ \\ DC & Output Source or Sink Current per Output Pin, $I_O$ & $\pm 25\text{mA}$ \\ DC & V_{CC}$ or Ground Current, $I_{CC}$ & $\pm 50\text{mA}$ \\ \hline \end{tabular}$

Temperature Range, T<sub>A</sub> . . . . . . . . . . . . . . . . . -55°C to 125°C

 2V
 1000ns (Max)

 4.5V
 500ns (Max)

 6V
 400ns (Max)

### **Thermal Information**

Thermal Resistance (Typical, Note 1) $\theta_{JA}$ (°C/W)
E (PDIP) Package
M (SOIC) Package58
PW (TSSOP) Package83
Maximum Junction Temperature
Maximum Storage Temperature Range65°C to 150°C
Maximum Lead Temperature (Soldering 10s)300°C (SOIC - Lead Tips Only)
1 27

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating, and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

### **DC Electrical Specifications**

Supply Voltage Range, V<sub>CC</sub>

Input Rise and Fall Time

		TES CONDI		V <sub>CC</sub>		25°C		-40°C T	O 85°C	-55°C T	O 125°C																															
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS																														
HC TYPES																																										
High Level Input	V <sub>IH</sub>	-	-	2	1.5	i	-	1.5	-	1.5	-	V																														
Voltage				4.5	3.15	•	-	3.15	-	3.15	-	V																														
				6	4.2	-	-	4.2	-	4.2	-	V																														
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	V																														
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V																														
				6	-	-	1.8	-	1.8	-	1.8	V																														
High Level Output	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	2	1.9	-	-	1.9	-	1.9	-	V																														
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V																														
OWO Edda			-0.02	6	5.9	-	-	5.9	-	5.9	-	V																														
High Level Output	1		-	-	-	-	-	-	-	-	-	V																														
Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V																														
112 20000			-7.8	6	5.48	-	-	5.34	-	5.2	-	V																														
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	2	-	-	0.1	-	0.1	-	0.1	V																														
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V																														
			0.02	6	-	-	0.1	-	0.1	-	0.1	V																														
Low Level Output	1																								l								-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads	ds		6	4.5	-	-	0.26	-	0.33	-	0.4	V																														
			7.8	6	-	-	0.26	-	0.33	-	0.4	V																														
Input Leakage Current	Ι <sub>Ι</sub>	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μА																														

### DC Electrical Specifications (Continued)

		TES CONDI		V <sub>CC</sub>		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μΑ
Three- State Leakage Current	V <sub>IL</sub> or V <sub>IH</sub>	V <sub>O</sub> =V <sub>CC</sub> or GND	-	6	-	-	±0.5	-	±5.0	-	±10	μΑ
HCT TYPES	•						•					
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	Voн	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	l <sub>l</sub>	V <sub>CC</sub> and GND	0	5.5	-		±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Three- State Leakage Current	V <sub>IL</sub> or V <sub>IH</sub>	V <sub>O</sub> =V <sub>CC</sub> or GND	-	6	-	-	±0.5	-	±5.0	-	±10	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI <sub>CC</sub> (Note 2)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

### NOTE:

### **HCT Input Loading Table**

	UNIT LOADS							
INPUT	HCT374	HCT574						
D0 - D7	0.3	0.4						
СР	0.9	0.75						
ŌĒ	1.3	0.6						

NOTE: Unit Load is  $\Delta I_{CC}$  limit specific in DC Electrical Specifications Table, e.g., 360 $\mu$ A max. at 25 $^{o}$ C.

<sup>2.</sup> For dual-supply systems, theoretical worst case ( $V_I = 2.4V$ ,  $V_{CC} = 5.5V$ ) specification is 1.8mA.

### **Prerequisite for Switching Specifications**

				25°C		-40	°C TO 8	5°C	-55 <sup>c</sup>	C TO 12	5°C	
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
HC TYPES	•											
Maximum Clock	f <sub>MAX</sub>	2	6	-	-	5	-	-	4	-	-	MHz
Frequency		4.5	30	-	-	25	-	-	20	-	-	MHz
		6	35	-	-	29	-	-	23	-	-	MHz
Clock Pulse Width	t <sub>W</sub>	2	80	-	-	100	-	-	120	-	-	ns
		4.5	16	-	-	20	-	-	24	-	-	ns
		6	14	-	-	17	-	-	20	-	-	ns
Setup Time Data to Clock	t <sub>SU</sub>	2	60	-	-	75	-	-	90	-	-	ns
		4.5	12	-	-	15	-	-	18	-	-	ns
		6	10	-	-	13	-	-	15	-	-	ns
Hold Time	t <sub>H</sub>	2	5	-	-	5	-	-	5	-	-	ns
Data to Clock		4.5	5	-	-	5	-	-	5	-	-	ns
		6	5	-	-	5	-	-	5	-	-	ns
HCT TYPES	•	•		•			•			•		
Maximum Clock Frequency	fMAX	4.5	30	-	-	25	-	-	20	-	-	MHz
Clock Pulse Width	t <sub>W</sub>	4.5	16	-	-	20	-	-	24	-	-	ns
Setup Time Data to Clock	t <sub>SU</sub>	4.5	12	-	-	15	-	-	18	-	-	ns
Hold Time Data to Clock	t <sub>H</sub>	4.5	5	-	-	5	-	-	5	-	-	ns

# **Switching Specifications** $C_L = 50 pF$ , Input $t_f$ , $t_f = 6 ns$

		TEST		25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay Clock to Output	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	165	-	205	-	250	ns
			4.5	-	-	33	-	41	-	50	ns
		C <sub>L</sub> = 15pF	5	1	15	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	28	-	35	-	43	ns
Output Disable to Q	t <sub>PLZ</sub> , t <sub>PHZ</sub>	C <sub>L</sub> = 50pF	2	-	-	135	-	170	-	205	ns
			4.5	1	-	27	-	34	-	41	ns
		C <sub>L</sub> = 15pF	5	-	11	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	23	-	29	-	35	ns

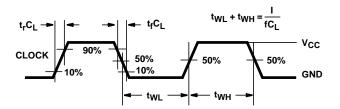
### Switching Specifications $C_L = 50pF$ , Input $t_r$ , $t_f = 6ns$ (Continued)

		TEST			25°C			С ТО °С		C TO 5°C	
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Output Enable to Q	t <sub>PZL</sub> , t <sub>PZH</sub>	C <sub>L</sub> = 50pF	2	-	-	150	-	190	-	225	ns
			4.5	-	-	30	-	38	-	45	ns
		C <sub>L</sub> = 15pF	5	-	12	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	26	-	33	-	38	ns
Maximum Clock Frequency	f <sub>MAX</sub>	C <sub>L</sub> = 15pF	5	-	60	-	-	-	-	-	MHz
Output Transition Time	t <sub>THL</sub> , t <sub>TLH</sub>	C <sub>L</sub> = 50pF	2	-	-	60	-	75	-	90	ns
			4.5	-	-	12	-	15	-	18	ns
			6	-	-	10	-	13	-	15	ns
Input Capacitance	Cl	C <sub>L</sub> = 50pF	-	10	-	10	-	10	-	10	pF
Three-State Output Capacitance	CO	-	-	20	-	20	-	20	-	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	C <sub>L</sub> = 15pF	5	-	39	-	-	-	-	-	pF
HCT TYPES					•						
Propagation Delay	t <sub>PHL</sub> , t <sub>PLH</sub>										
Clock to Output		C <sub>L</sub> = 50pF	4.5	-	-	33	-	41	-	50	ns
		C <sub>L</sub> = 15pF	5	-	15	-	-	-	-	-	ns
Output Disable to Q	t <sub>PLZ</sub> , t <sub>PHZ</sub>	$C_L = 50pF$	4.5	-	-	28	-	35	-	42	ns
		$C_L = 15pF$	5	-	11	-	-	-	-	-	ns
Output Enable to Q	t <sub>PZL</sub> , t <sub>PZH</sub>	$C_L = 50pF$	4.5	-	-	30	-	38	-	45	ns
		C <sub>L</sub> = 15pF	5	-	12	-	-	-	-	-	ns
Maximum Clock Frequency	f <sub>MAX</sub>	C <sub>L</sub> = 15pF	5	-	60	-	-	-	-	-	MHz
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	12	-	15	-	18	ns
Input Capacitance	Cl	C <sub>L</sub> = 50pF	-	10	-	10	-	10	-	10	pF
Three-State Output Capacitance	co	-	-	20	-	20	-	20	-	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	C <sub>L</sub> = 15pF	5	-	47	-	-	-	-	-	pF

<sup>3.</sup>  $\ensuremath{C_{\text{PD}}}$  is used to determine the dynamic power consumption, per package.

<sup>4.</sup> P<sub>D</sub> = C<sub>PD</sub> V<sub>CC</sub><sup>2</sup> f<sub>i</sub> + Σ V<sub>CC</sub><sup>2</sup> f<sub>O</sub> C<sub>L</sub> where f<sub>i</sub> = Input Frequency, f<sub>O</sub> = Output Frequency, C<sub>L</sub> = Output Load Capacitance, V<sub>CC</sub> = Supply Voltage.

### Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V $_{CC}$  to 90% V $_{CC}$  in accordance with device truth table. For f $_{MAX}$ , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

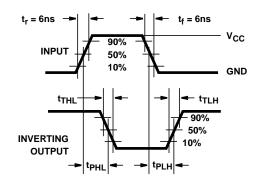


FIGURE 3. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

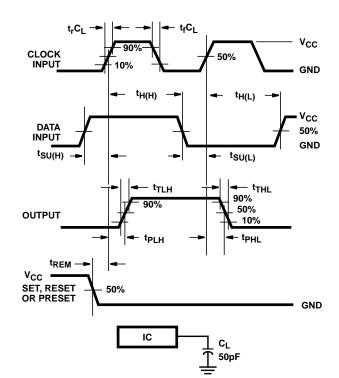
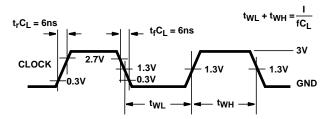


FIGURE 5. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS



NOTE: Outputs should be switching from 10% V $_{CC}$  to 90% V $_{CC}$  in accordance with device truth table. For f $_{MAX}$ , input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

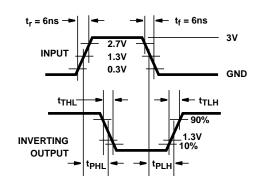


FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

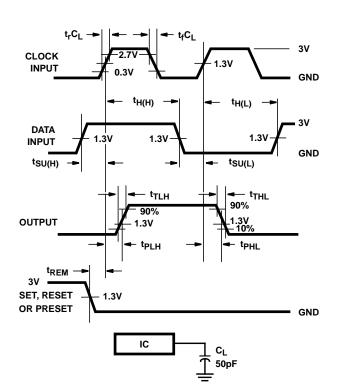
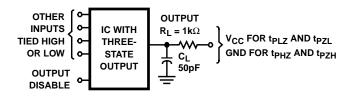


FIGURE 6. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

### Test Circuits and Waveforms (Continued) 6ns 3V V<sub>CC</sub> OUTPUT OUTPUT 90% **DISABLE** 50% DISABLE 10% 0.3 GND GND t<sub>PZL</sub> → - t<sub>PLZ</sub> → t<sub>PZL</sub> ► t<sub>PLZ</sub> → **OUTPUT LOW** OUTPUT LOW 50% TO OFF TO OFF 1.3V 10% 10% ◆ t<sub>PHZ</sub> ◆ - t<sub>PZH</sub> · t<sub>PHZ</sub> → tpzh -90% 90% **OUTPUT HIGH OUTPUT HIGH** 50% TO OFF TO OFF 1.3V OUTPUTS **OUTPUTS OUTPUTS OUTPUTS OUTPUTS OUTPUTS ENABLED** ENABLED **DISABLED ENABLED** DISABLED

FIGURE 7. HC THREE-STATE PROPAGATION DELAY **WAVEFORM** 

FIGURE 8. HCT THREE-STATE PROPAGATION DELAY **WAVEFORM** 



**ENABLED** 

NOTE: Open drain waveforms  $t_{PLZ}$  and  $t_{PZL}$  are the same as those for three-state shown on the left. The test circuit is Output  $R_L = 1k\Omega$  to  $V_{CC}$ ,  $C_L = 50pF$ .

FIGURE 9. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT



7-May-2012

### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
5962-8974201RA	ACTIVE	CDIP	J	20	1	TBD	Call TI	Call TI	
CD54HC374F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
CD54HC574F	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
CD54HC574F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
CD54HCT374F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
CD54HCT574F	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
CD54HCT574F3A	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
CD74HC374E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HC374EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HC374M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC374M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC374M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC374M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC374ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC374MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC574E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HC574EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HC574M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC574M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC574M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC574M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
CD74HC574ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC574MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT374E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HCT374EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HCT374M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT374M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT374M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT374M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT374ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT374MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT574E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HCT574EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HCT574M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT574M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT574M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT574M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT574ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT574MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT574PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



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### PACKAGE OPTION ADDENDUM

7-May-2012

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
CD74HCT574PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT574PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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### OTHER QUALIFIED VERSIONS OF CD54HC374, CD54HC574, CD54HCT374, CD54HCT574, CD74HC374, CD74HC574, CD74HC7374, CD74HC

- Catalog: CD74HC374, CD74HC574, CD74HCT374, CD74HCT574
- Automotive: CD74HCT574-Q1, CD74HCT574-Q1
- Enhanced Product: CD74HCT574-EP, CD74HCT574-EP



7-May-2012

• Military: CD54HC374, CD54HC574, CD54HCT374, CD54HCT574

NOTE: Qualified Version Definitions:

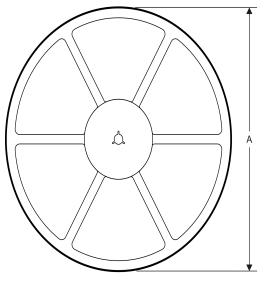
- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

### PACKAGE MATERIALS INFORMATION

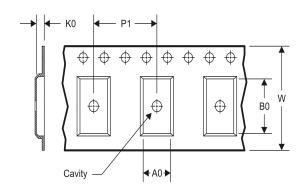
14-Jul-2012 www.ti.com

### TAPE AND REEL INFORMATION

### **REEL DIMENSIONS**



### **TAPE DIMENSIONS**



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### TAPE AND REEL INFORMATION

### \*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC374M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CD74HC574M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CD74HCT374M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CD74HCT574M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CD74HCT574PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

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\*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC374M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HC574M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HCT374M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HCT574M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HCT574PWR	TSSOP	PW	20	2000	367.0	367.0	38.0

### 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

### PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

### PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G20)

### PLASTIC SMALL OUTLINE

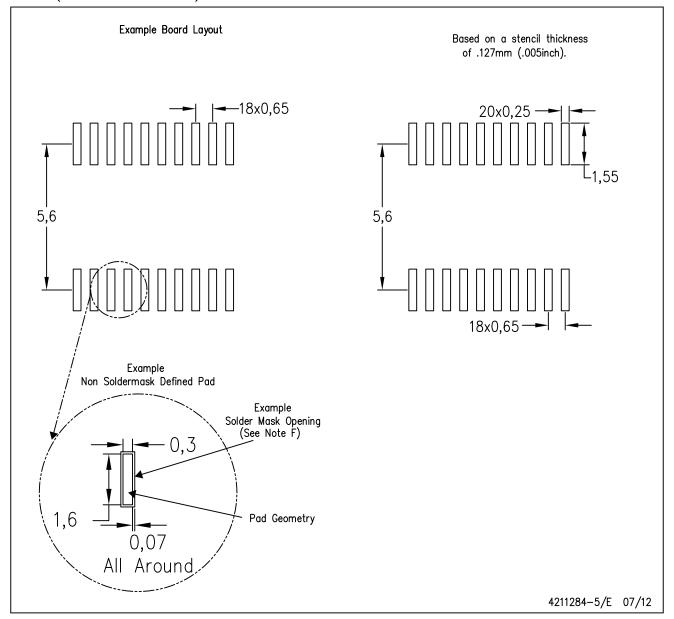


- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G20)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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